

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL TYPE

# 2SD1947A

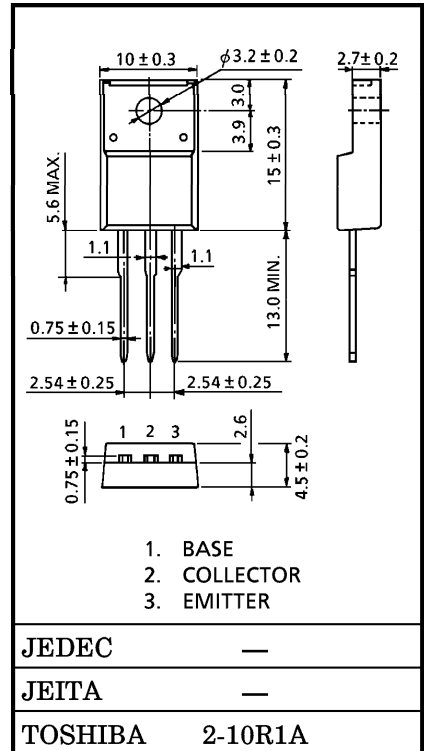
HIGH CURRENT SWITCHING APPLICATIONS  
LAMP, SOLENOID DRIVE APPLICATIONS

- High DC Current Gain :  $h_{FE} = 500 \sim 1500$  ( $I_C = 1A$ )
- Low Collector Saturation Voltage :  $V_{CE(sat)} = 0.3V$  (Max.) ( $I_C = 5A$ )

MAXIMUM RATINGS ( $T_c = 25^\circ C$ )

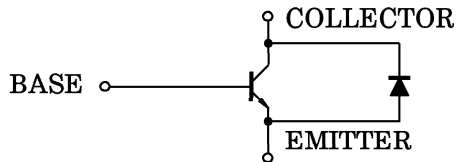
CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{CBO}$	100	V
Collector-Emitter Voltage	$V_{CEO}$	100	V
Emitter-Base Voltage	$V_{EBO}$	7	V
Collector Current	DC	$I_C$	10
	Pulse	$I_{CP}$	15
Base Current	$I_B$	2	A
Collector Power Dissipation	$P_C$	$T_a = 25^\circ C$	2.0
		$T_c = 25^\circ C$	40
Junction Temperature	$T_j$	150	$^\circ C$
Storage Temperature Range	$T_{stg}$	-55~150	$^\circ C$

Unit in mm



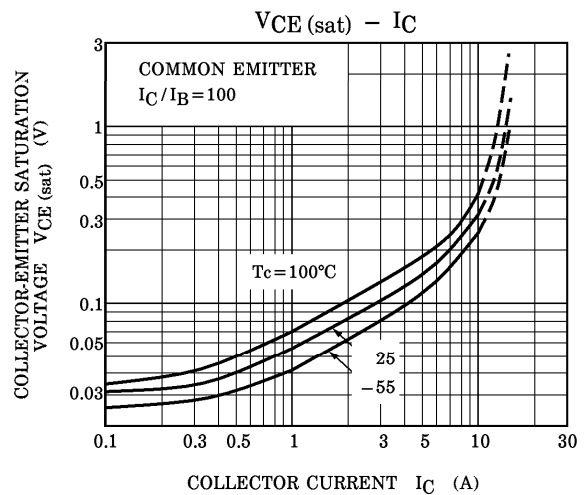
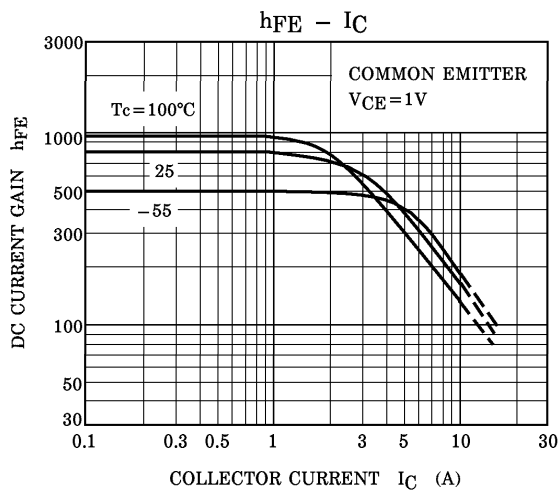
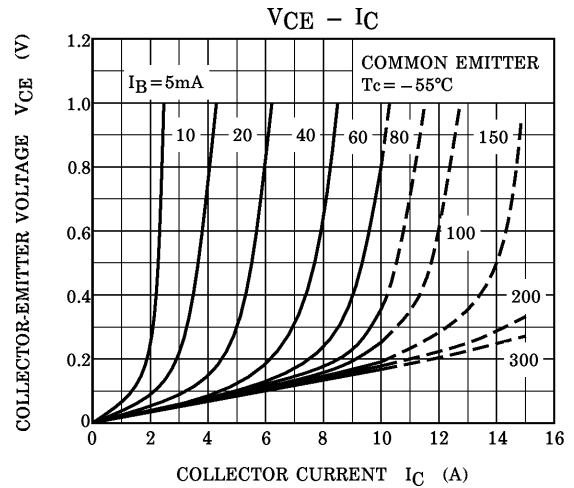
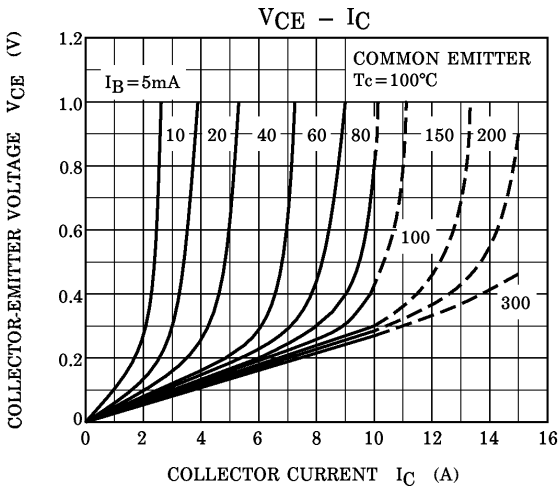
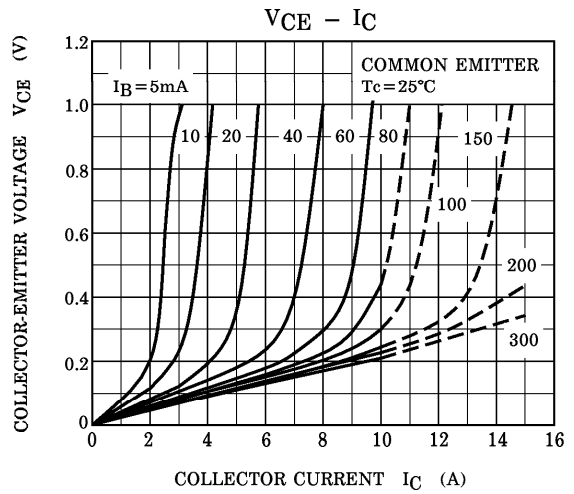
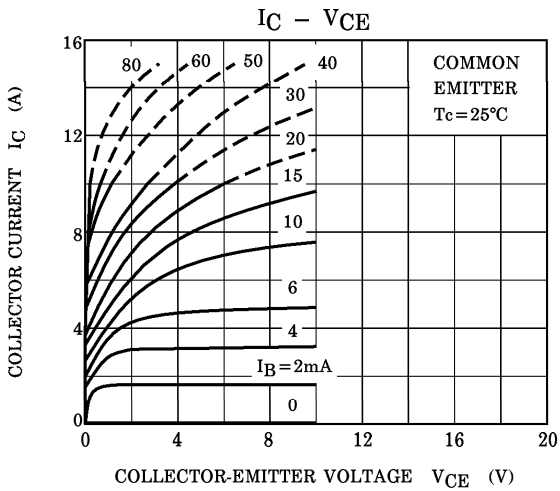
Weight : 1.7 g (Typ.)

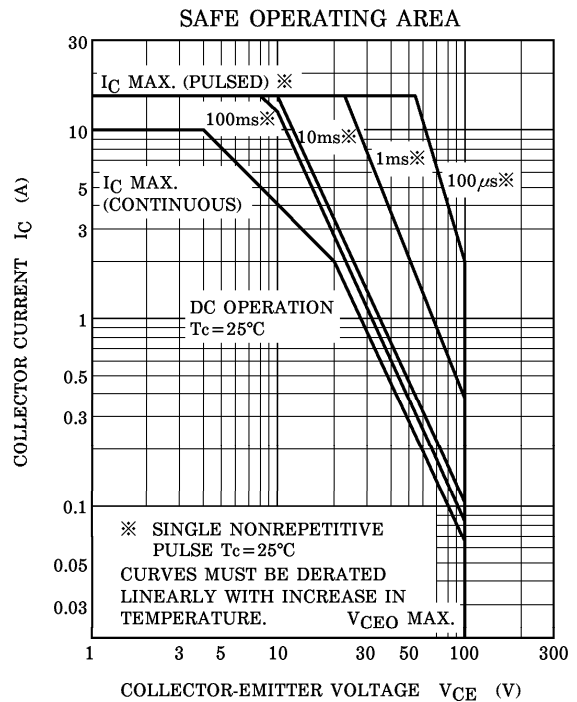
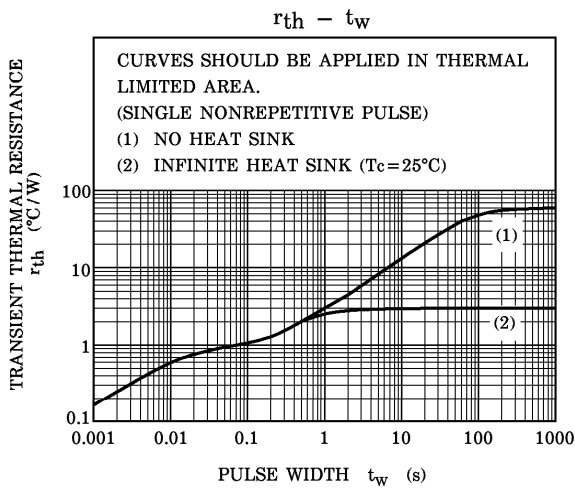
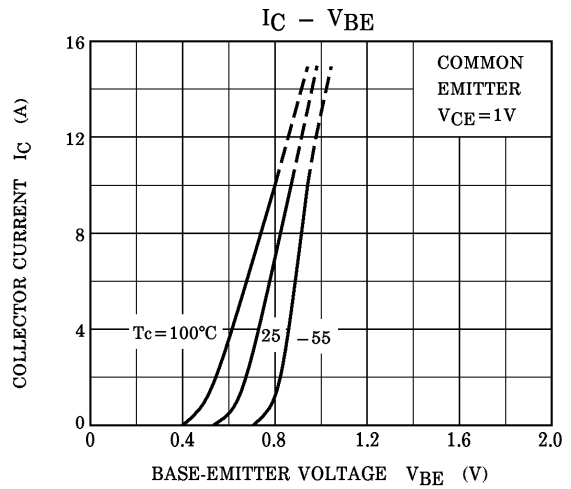
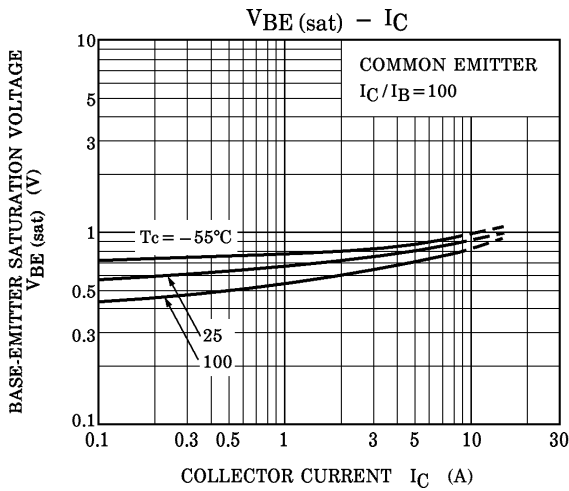
EQUIVALENT CIRCUIT



ELECTRICAL CHARACTERISTICS (T<sub>c</sub> = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		I <sub>CBO</sub>	V <sub>CB</sub> = 100V, I <sub>E</sub> = 0	—	—	10	μA
Emitter Cut-off Current		I <sub>EBO</sub>	V <sub>EB</sub> = 7V, I <sub>C</sub> = 0	—	—	10	μA
Collector-Emitter Breakdown Voltage		V <sub>(BR)CEO</sub>	I <sub>C</sub> = 50mA, I <sub>B</sub> = 0	100	—	—	V
DC Current Gain		h <sub>FE</sub> (1)	V <sub>CE</sub> = 1V, I <sub>C</sub> = 1A	500	—	1500	
		h <sub>FE</sub> (2)	V <sub>CE</sub> = 1V, I <sub>C</sub> = 5A	150	—	—	
Collector-Emitter Saturation Voltage		V <sub>CE(sat)</sub>	I <sub>C</sub> = 5A, I <sub>B</sub> = 0.05A	—	—	0.3	V
Base-Emitter Saturation Voltage		V <sub>BE(sat)</sub>	I <sub>C</sub> = 5A, I <sub>B</sub> = 0.05A	—	—	1.2	V
Collector-Emitter Forward Voltage		V <sub>ECF</sub>	I <sub>E</sub> = 5A, I <sub>B</sub> = 0	—	—	2.0	V
Transition Frequency		f <sub>T</sub>	V <sub>CE</sub> = 5V, I <sub>C</sub> = 1A	—	70	—	MHz
Collector Output Capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f = 1MHz	—	160	—	pF
Switching Time	Turn-on Time	t <sub>on</sub>	<p> <math>I_{B1} = -I_{B2} = 0.05A</math>,  DUTY CYCLE <math>\leq 1\%</math>  <math>V_{CC} = 30V</math> </p>	—	0.5	—	μs
	Storage Time	t <sub>stg</sub>		—	6.0	—	
	Fall Time	t <sub>f</sub>		—	1.0	—	





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